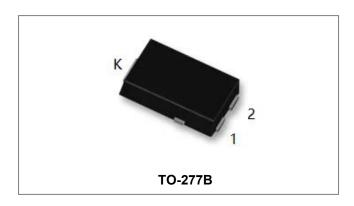
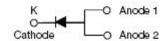




ST5150S SCHOTTKY RECTIFIER



Circuit Diagram



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	150	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =105°C, rectangular wave form	5	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T _c = 25 °C	80	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 2A, Pulse, T _J = 25 °C	0.68	0.70	\ \
	V F1	@ 5A, Pulse, T _J = 25 °C	1.09	1.20	V
	V	@ 2A, Pulse, T _J = 125 °C	0.55	0.60	\ \
	V_{F2}	@ 5A, Pulse, T _J = 125 °C	0.69	0.80	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_{R_1} T_J = 25 ^{\circ}\text{C}$	0.001	0.1	mA
	I _{R2}	$@V_R = \text{rated } V_{R_1} T_J = 125 ^{\circ}\text{C}$	3	15	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	200	-	pF
Voltage Rate of Change	dv/dt	-	•	10,000	V/μs

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

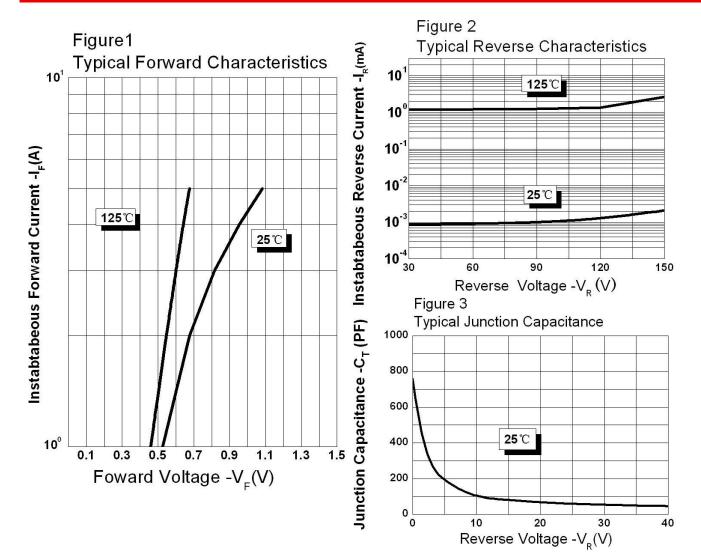




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	-	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$		70	°C/W
Approximate Weight	wt	-	0.08	g

Ratings and Characteristics Curves



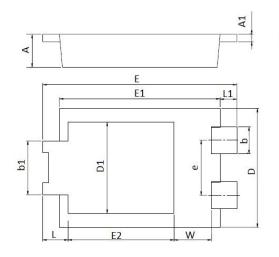
[•] China - Germany - Korea - Singapore - United States •

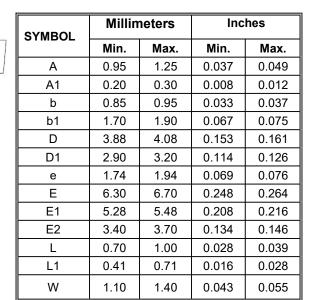
http://www.smc-diodes.com - sales@ smc-diodes.com •



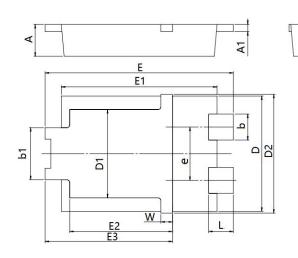


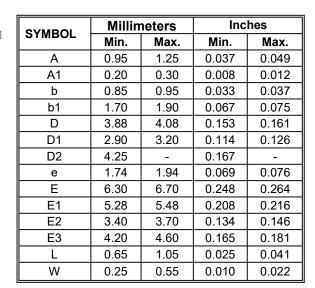
Mechanical Dimensions TO-277B





Mechanical Dimensions TO-277B(New)





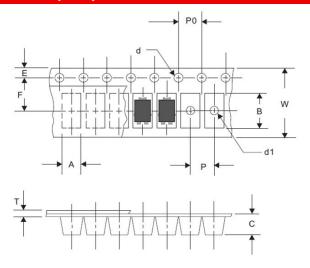
Notes: New Mechanical Dimensions is performed from date code 2236X.

[•] http://www.smc-diodes.com - sales@ smc-diodes.com •





Carrier Tape Specification TO-277B



SYMBOL	Millimeters		
STWIBOL	Min.	Max.	
Α	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

Ordering Information

Device	Package	Shipping
ST5150S	TO-277B(Pb-Free)	5000pcs/ reel
ST5150STR	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 ST
 = Device Type

 5
 = Forward Current (5A)

 150
 = Reverse Voltage (150V)

 S
 = Package type

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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